imall

Chipsmall Limited consists of a professional team with an average of over 10 year of expertise in the distribution of electronic components. Based in Hongkong, we have already established firm and mutual-benefit business relationships with customers from, Europe, America and south Asia, supplying obsolete and hard-to-find components to meet their specific needs.

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Schottky Barrier Diodes

Schottky barrier diodes are designed primarily for high-efficiency UHF and VHF detector applications. Readily available to many other fast switching RF and digital applications. They are housed in the SOT-323/SC-70 package which is designed for low-power surface mount applications.

Features

- Extremely Low Minority Carrier Lifetime
- Very Low Capacitance
- Low Reverse Leakage
- Available in 8 mm Tape and Reel
- AEC Qualified and PPAP Capable
- S Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements
- These Devices are Pb-Free, Halogen Free/BFR Free and are RoHS Compliant*

MAXIMUM RATINGS

Rating	Symbol	Value	Unit
Reverse Voltage MMBD330T1G, SMMBD330T1G MMBD770T1G, SMMBD770T1G	V _R	30 70	Vdc
Forward Continuous Current (DC)	١ _F	200	mA
Nonrepetitive Peak Forward Current (Note 1)	I _{FSM}	1.0	A
Forward Power Dissipation $T_A = 25^{\circ}C$	P _F	120	mW
Junction Temperature	TJ	-55 to +125	°C
Storage Temperature Range	T _{stg}	-55 to +150	°C

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

1. 60 Hz Halfsine.



ON Semiconductor®

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SC-70/SOT-323 **CASE 419**

-0 3 1 0-

MARKING DIAGRAMS



XX	= Specific Device Code
4T	= MMBD330T1

=	MMBD	330T
---	------	------

= MMBD770T1

5H

Μ

= Date Code

(Note: Microdot may be in either location)

*Date Code orientation may vary depending upon the manufacturing location.

ORDERING INFORMATION

Device	Package	Shipping [†]			
MMBD330T1G	SC–70 (Pb–Free)	3,000/Tape & Reel			
SMMBD330T1G	SC–70 (Pb–Free)	3,000/Tape & Reel			
MMBD770T1G	SC–70 (Pb–Free)	3,000/Tape & Reel			
SMMBD770T1G	SC–70 (Pb–Free)	3,000/Tape & Reel			

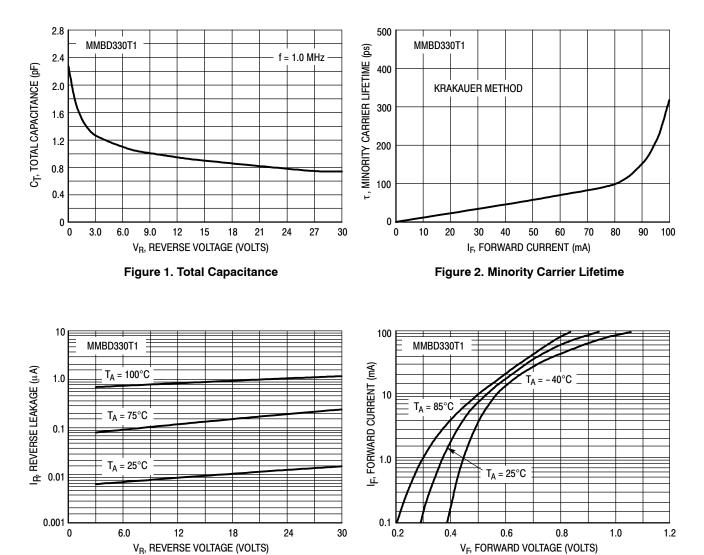
+For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

⁼ Pb-Free Package

Min Unit Characteristic Symbol Тур Max $V_{(BR)R}$ Reverse Breakdown Voltage Volts $(I_{R} = 10 \ \mu A)$ MMBD330T1G, SMMBD330T1G MMBD770T1G, SMMBD770T1G 30 _ 70 _ _ Diode Capacitance C_T рF (V_R = 15 Volts, f = 1.0 MHZ) MMBD330T1G, SMMBD330T1G 0.9 1.5 (V_R = 20 Volts, f = 1.0 MHZ) MMBD770T1G, SMMBD770T1G 0.5 1.0 _ **Reverse Leakage** nAdc I_R (V_R = 25 V) MMBD330T1G, SMMBD330T1G 200 13 _ (V_R = 35 V) MMBD770T1G, SMMBD770T1G _ 9.0 200 Forward Voltage VF Vdc (I_F = 1.0 mAdc) MMBD330T1G, SMMBD330T1G 0.38 0.45 _ $(I_{F} = 10 \text{ mA})$ _ 0.52 0.60 (I_F = 1.0 mÁdc) MMBD770T1G, SMMBD770T1G _ 0.42 0.50 $(I_{F} = 10 \text{ mA})$ _ 0.70 1.0

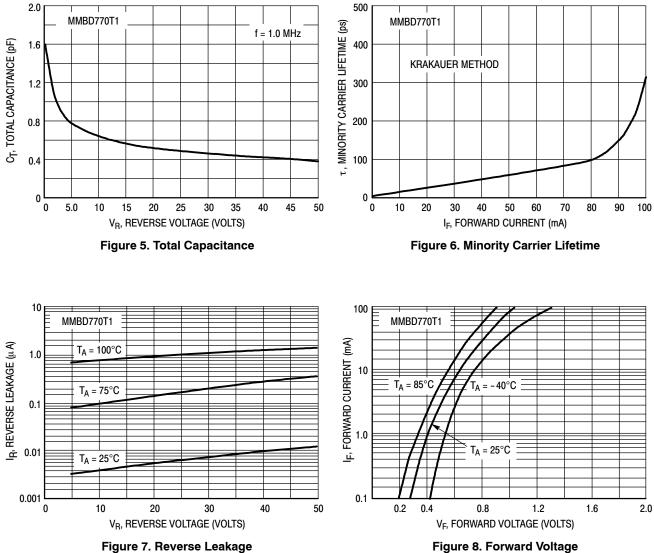
ELECTRICAL CHARACTERISTICS (T_A = 25°C unless otherwise noted)



TYPICAL CHARACTERISTICS MMBD330T1G, SMMBD330T1G

Figure 3. Reverse Leakage

Figure 4. Forward Voltage

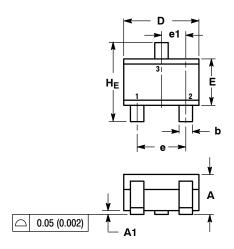


TYPICAL CHARACTERISTICS MMBD770T1G, SMMBD770T1G

Figure 8. Forward Voltage

PACKAGE DIMENSIONS

SC-70 (SOT-323) CASE 419-04 ISSUE N

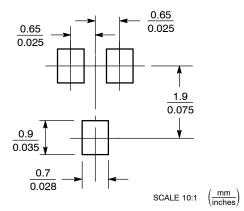


NOTES: 1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982. 2. CONTROLLING DIMENSION: INCH.

	MILLIMETERS			INCHES		
DIM	MIN	NOM	MAX	MIN	NOM	MAX
Α	0.80	0.90	1.00	0.032	0.035	0.040
A1	0.00	0.05	0.10	0.000	0.002	0.004
A2	0.70 REF			0.028 REF		
b	0.30	0.35	0.40	0.012	0.014	0.016
с	0.10	0.18	0.25	0.004	0.007	0.010
D	1.80	2.10	2.20	0.071	0.083	0.087
Е	1.15	1.24	1.35	0.045	0.049	0.053
е	1.20	1.30	1.40	0.047	0.051	0.055
e1	0.65 BSC			0.026 BSC		
L	0.20	0.38	0.56	0.008	0.015	0.022
HE	2.00	2.10	2.40	0.079	0.083	0.095



SOLDERING FOOTPRINT*



*For additional information on our Pb–Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

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